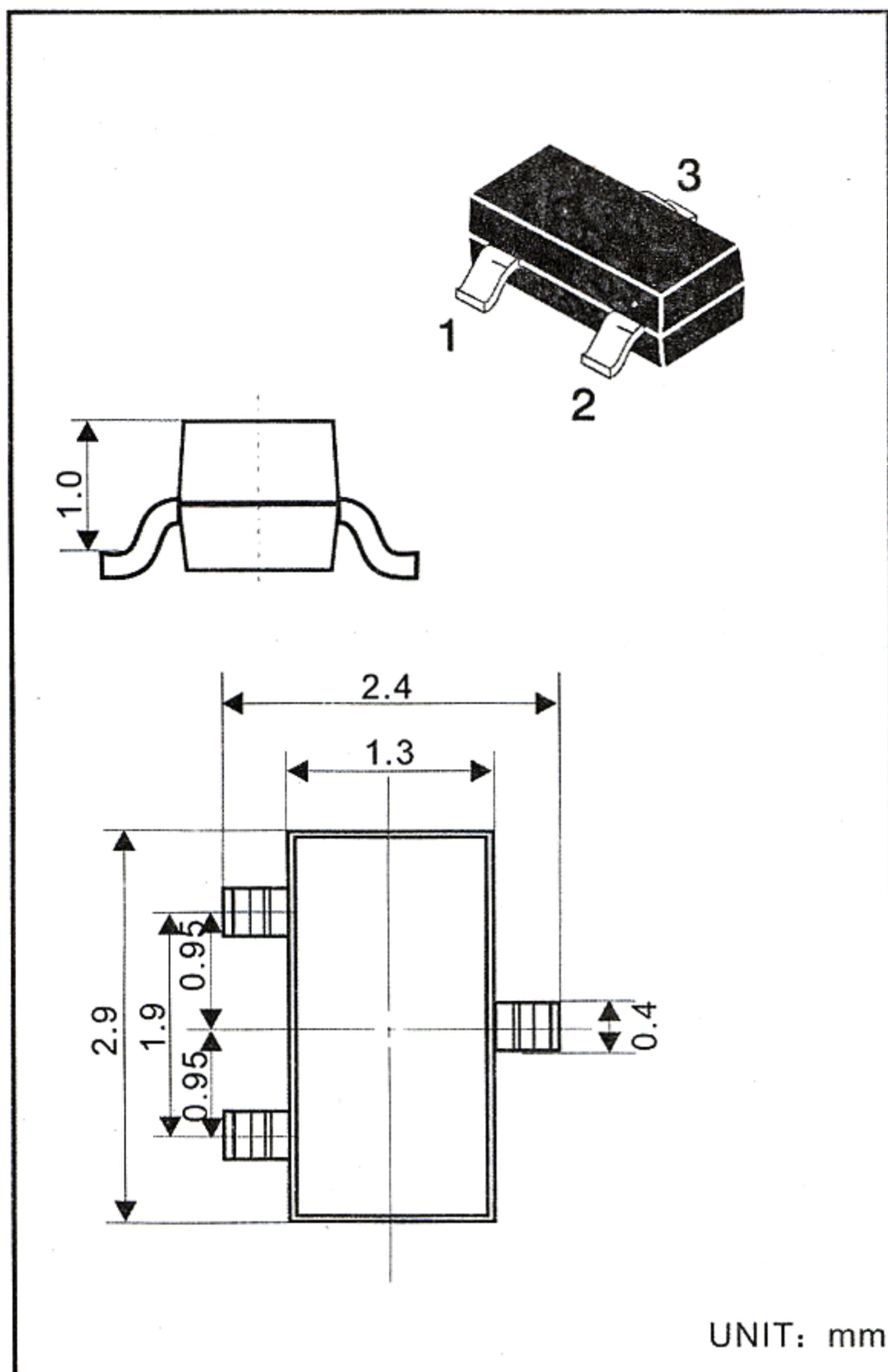


SOT-23 Plastic-Encapsulate DIODES

BAV70LT1 SWITCHING DIODE



FEATURES

Power dissipation

PD: 225mW (Tamb=25°C)

Forward current

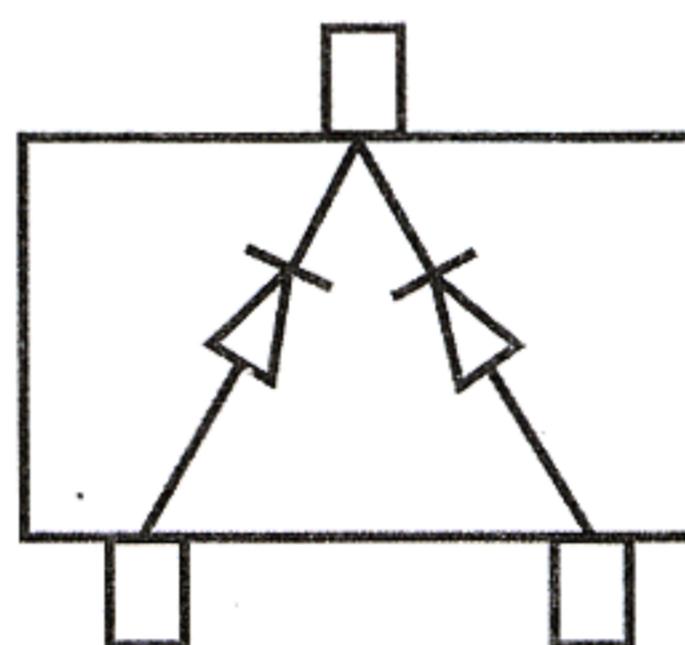
IF: 200mA

Reverse voltage

VR: 70V

Operating and storage junction temperature range

TJ,Tstg : -55°C to +150°C



MARKING: A4

ELECTRICAL CHARACTERISTICS

(Tamp=25°C unless otherwise specified)

Parameter	Symbol	Test conditions	MIN	MAX	UNIT
Reverse breakdown voltage	V _(BR)	I _R =100 μA	70		V
Reverse voltage leakage current	I _R	VR=70V		2.5	μA
Forward voltage	V _F	I _F =1mA I _F =10mA I _F =50mA I _F =150mA	715 855 1000 1250		mV
Diode capacitance	C _{tot}	VR=0V, f=1MHz		1.5	pF
Reverse recovery time	t _{rr}	I _F =I _R =10mA I _{rr} =0.1I _R		6	ns